

### SPREAD SPECTRUM CLOCK SYNTHESIZER

#### IDT5P50911/2/3/4

### **Description**

The IDT5P50911/2/3/4 is a family of 1.8V/2.5V/3.3V low power, spread spectrum clock generators capable of reducing EMI radiation from an input clock. Spread spectrum technique is capable of reducing the harmonic frequency amplitude peaks by several dB.

## **Ordering Information**

#### **Output Frequency**

5 to 15 MHz - 5P50911NBGI/5P50911DVGI 10 to 30 MHz - 5P50912NBGI/5P50912DVGI 20 to 60 MHz - 5P50913NBGI/5P50913DVGI 40 to 120 MHz - 5P50914NBGI/5P50914DVGI

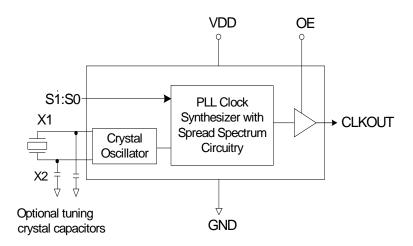
#### **Features**

- 8-pin DFN package (2x2mm)
  8-pin MSOP package (3x4.9mm)
- Provides a spread spectrum output clock
- Crystal input frequency range of 10 to 30 MHz
- Output frequency range of 10 to 120 MHz
- Center and down spread
- Peak reduction by 8 dB to 16 dB typical on 3rd through 19th odd harmonics
- Low EMI feature can be disabled
- Operating voltage of 1.8 V, 2.5 or 3.3V
- RoHS 6 compliant package

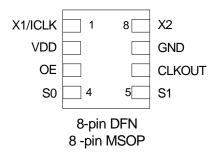
#### **Spread Modulation Frequency Table**

| Part<br>Number | Output<br>Multiply | Input<br>(MHz) | Modulation<br>(kHz) | Input<br>(MHz) | Modulation<br>(kHz) | Modulation<br>Frequency (kHz) |
|----------------|--------------------|----------------|---------------------|----------------|---------------------|-------------------------------|
| 5P50911        | 1/2x               |                |                     |                |                     | Input frequency               |
| 5P50912        | 1x                 | 10             | 27                  | 30             | 81                  | *27/10000                     |
| 5P50913        | 2x                 |                |                     |                |                     |                               |
| 5P50914        | 4x                 |                |                     |                |                     |                               |

### **Block Diagram**



# **Pin Assignment**



# **Spread Direction and Percentage Select Table**

| S1 | S0 | Spread<br>Direction | Spread<br>Percentage |
|----|----|---------------------|----------------------|
| 0  | 0  | OFF                 |                      |
| 0  | 1  | Center              | ±0.5                 |
| 1  | 0  | Center              | ±1.5                 |
| 1  | 1  | Down                | -0.5                 |

# **Pin Description**

| Pin<br>Number | Pin<br>Name | Pin Type | Pin Description  |
|---------------|-------------|----------|--|
| 1             | X1          | ΧI       | Crystal input. Connect this pin to a crystal.  |
| 2             | VDD         | Power    | Voltage supply. Connect to 1.8 V ±0.1 V, 2.5 V ±10% or 3.3 V ±10%,   |
| 3             | OE          | Input    | Output enable. Tri-states CLK output when low. Internal pull-up.   |
| 4             | S0          | Input    | Function select 0 input. Selects spread amount and direction per table above. Internal pull-down resistor. |
| 5             | S1          | Input    | Function select 1 input. Selects spread amount and direction per table above. Internal pull-down resistor. |
| 6             | CLKOUT      | Output   | Clock output. Weal pull-down when OE low.  |
| 7             | GND         | Power    | Connect to ground.   |
| 8             | X2          | XO       | Crystal output. Connect this pin to a crystal.   |

### **External Components**

#### **Decoupling Capacitor**

As with any high-performance mixed-signal IC, the IDT5P50911/2/3/4 must be isolated from system power supply noise to perform optimally.

A decoupling capacitor of 0.01µF must be connected between each VDD and the PCB ground plane.

#### **Series Termination Resistor**

Clock output traces over one inch should use series termination. To series terminate a  $50\Omega$  trace (a commonly used trace impedance), place a  $33\Omega$  resistor in series with the clock line, as close to the clock output pin as possible. The nominal impedance of the clock output is  $20\Omega$ .

#### **Crystal Load Capacitors**

The device crystal connections should include pads for small capacitors from X1 to ground and from X2 to ground. These capacitors are used to adjust the stray capacitance of the board to match the nominally required crystal load capacitance. Because load capacitance can only be increased in this trimming process, it is important to keep stray capacitance to a minimum by using very short PCB traces (and no vias) between the crystal and device. Crystal capacitors, if needed, must be connected from each of the pins X1 and X2 to ground.

The value (in pF) of these crystal caps should equal ( $C_L$  -12 pF)\*2. In this equation,  $C_L$ = crystal load capacitance in pF. Example: For a crystal with a 16 pF load capacitance, each crystal capacitor would be 8 pF [(16-12) x 2 = 8].

#### **PCB Layout Recommendations**

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

- 1) The  $0.01\mu F$  decoupling capacitors should be mounted on the component side of the board as close to the VDD pin as possible. No vias should be used between the decoupling capacitors and VDD pins. The PCB trace to VDD pins should be kept as short as possible, as should the PCB trace to the ground via.
- 2) To minimize EMI, the  $33\Omega$  series termination resistor (if needed) should be placed close to the clock output.

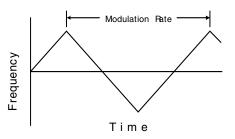
3) An optimum layout is one with all components on the same side of the board, minimizing vias through other signal layers. Other signal traces should be routed away from the IDT5P50911/2/3/4. This includes signal traces just underneath the device, or on layers adjacent to the ground plane layer used by the device.

#### **Spread Spectrum Profile**

The IDT5P50911/2/3/4 is a low EMI clock generator using an optimized frequency slew rate algorithm to facilitate down stream tracking of zero delay buffers and other PLL devices.

The modulation rate is directly relate to the input crystal frequency.

For input frequency ICLK, then use the modulation frequency indicated for the part below.



Modulation Frequency = Input Frequency/10000

Ex. Input Frequency = 20 MHz Modulation Frequency = 20 MHz/10000 = 2 kHz

### **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the IDT5P50911/2/3/4. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

| Item                          | Rating               |
|-------------------------------|----------------------|
| Supply Voltage, VDD           | -0.5 V to 7.0 V      |
| All Inputs                    | -0.5 V to VDD +0.5 V |
| Ambient Operating Temperature | -40 to +85°C         |
| Storage Temperature           | -50 to +150°C        |
| Junction Temperature          | 125°C                |
| Soldering Temperature         | 260°C                |

## **Recommended Operation Conditions**

| Parameter   | Min.  | Тур. | Max.  | Units |
|---|-------|------|-------|-------|
| Ambient Operating Temperature                         | -40   |      | +85   | °C    |
| Power Supply Voltage VDD (measured in respect to GND) | +1.7  | +1.8 | +1.9  | V     |
|   | +2.25 | +2.5 | +2.75 | V     |
|   | +2.97 | +3.3 | +3.63 | V     |

### **DC Electrical Characteristics**

Unless stated otherwise, **VDD = 1.8 V \pm0.1 V.** Ambient Temperature -40 to +85°C

| Parameter                      | Symbol          | Conditions               | Min.      | Тур. | Max.      | Units |
|--------------------------------|-----------------|--------------------------|-----------|------|-----------|-------|
| Operating Voltage              | VDD             |                          | 1.7       | 1.8  | 1.9       | V     |
| Input High Voltage             | V <sub>IH</sub> | ICLK, S2:S0              | VDD x 0.8 |      | VDD + 0.3 | V     |
| Input Low Voltage              | V <sub>IL</sub> | ICLK, S2:S0              | GND       |      | VDD x 0.2 | V     |
| Output High Voltage            | V <sub>OH</sub> | I <sub>OH</sub> = -18 mA | VDD x 0.9 | VDD  |           | V     |
| Output Low Voltage             | V <sub>OL</sub> | I <sub>OL</sub> = 18 mA  |           | GND  | VDD x 0.1 | V     |
| IDD                            |                 | No load                  |           | TBD  |           |       |
| Input Capacitance              |                 |                          |           | 5    |           | pF    |
| Load Capacitance               |                 |                          |           | 5    |           | pF    |
| Internal Pull-up<br>Resistor   | R <sub>PU</sub> | OE                       |           | 400  | 520       | kΩ    |
| Internal Pull-down<br>Resistor | R <sub>PD</sub> | S1:S0, CLKOUT            |           | 400  | 520       | kΩ    |

Unless stated otherwise, **VDD = 2.5 V ±10%.** Ambient Temperature -40 to +85°C

| Parameter                      | Symbol          | Conditions               | Min.      | Тур. | Max.      | Units |
|--------------------------------|-----------------|--------------------------|-----------|------|-----------|-------|
| Operating Voltage              | VDD             |                          | 2.25      | 2.5  | 2.75      | V     |
| Input High Voltage             | V <sub>IH</sub> | ICLK, S2:S0              | VDD x 0.8 |      | VDD + 0.3 | V     |
| Input Low Voltage              | V <sub>IL</sub> | ICLK, S2:S0              | GND       |      | VDD x 0.2 | V     |
| Output High Voltage            | V <sub>OH</sub> | I <sub>OH</sub> = -25 mA | VDD x 0.9 | VDD  |           | V     |
| Output Low Voltage             | V <sub>OL</sub> | I <sub>OL</sub> = 25 mA  |           | GND  | VDD x 0.1 | V     |
| IDD                            |                 | No load                  |           | TBD  |           |       |
| Input Capacitance              |                 |                          |           | 5    |           | pF    |
| Load Capacitance               |                 |                          |           | 5    |           | pF    |
| Internal Pull-up<br>Resistor   | R <sub>PU</sub> | OE                       |           | 300  | 390       | kΩ    |
| Internal Pull-down<br>Resistor | R <sub>PD</sub> | S1:S0, CLKOUT            |           | 300  | 390       | kΩ    |

Unless stated otherwise, VDD = 3.3 V ±10%. Ambient Temperature -40 to +85°C

| Parameter           | Symbol          | Conditions               | Min.      | Тур. | Max.      | Units |
|---------------------|-----------------|--------------------------|-----------|------|-----------|-------|
| Operating Voltage   | VDD             |                          | 2.97      | 3.3  | 3.63      | V     |
| Input High Voltage  | V <sub>IH</sub> | ICLK, S2:S0              | VDD x 0.8 |      | VDD + 0.3 | V     |
| Input Low Voltage   | $V_{IL}$        | ICLK, S2:S0              | GND       |      | VDD x 0.2 | V     |
| Output High Voltage | V <sub>OH</sub> | I <sub>OH</sub> = -33 mA | VDD x 0.9 | VDD  |           | V     |
| Output Low Voltage  | V <sub>OL</sub> | I <sub>OL</sub> = 33 mA  |           | GND  | VDD x 0.1 | V     |
| IDD                 |                 | No load                  |           | TBD  |           |       |
| Input Capacitance   |                 |                          |           | 5    |           | pF    |

| Parameter                      | Symbol          | Conditions    | Min. | Тур. | Max. | Units |
|--------------------------------|-----------------|---------------|------|------|------|-------|
| Load Capacitance               |                 |               |      | 5    |      | pF    |
| Internal Pull-up<br>Resistor   | R <sub>PU</sub> | OE            |      | 200  | 260  | kΩ    |
| Internal Pull-down<br>Resistor | R <sub>PD</sub> | S1:S0, CLKOUT |      | 200  | 260  | kΩ    |

### **AC Electrical Characteristics**

Unless stated otherwise, VDD = 1.8 V ±0.1 V, 2.5 V ±10% or 3.3 V ±10%. Ambient Temperature -40 to +85°C

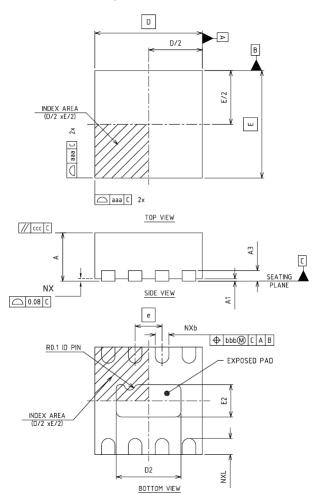
| Parameter                  | Symbol          | Conditions                        | Min. | Тур. | Max. | Units |
|----------------------------|-----------------|-----------------------------------|------|------|------|-------|
| Output Clock Duty Cycle    |                 |                                   | 45   | 50   | 55   | %     |
| Output Rise Time           | t <sub>OR</sub> | 20% to 80%, Note 1                |      | 1.2  |      | ns    |
| Output Fall Time           | t <sub>OF</sub> | 80% to 20%, Note 1                |      | 1.2  |      | ns    |
| Spread Spectrum Modulation |                 | 5 to 15 MHz output (IDT5P50911)   | 27   |      | 81   | kHz   |
| Rate                       |                 | 10 to 30 MHz output (IDT5P50912)  | 27   |      | 81   | kHz   |
|                            |                 | 20 to 60 MHz output (IDT5P50913)  | 27   |      | 81   | kHz   |
|                            |                 | 40 to 120 MHz output (IDT5P50914) | 27   |      | 81   | kHz   |
| Jitter Cycle to Cycle      |                 | Cycle to cycle jitter             |      | 150  |      | ps    |
| Output Settling Time       |                 | Note 2                            |      |      | 3.0  | ms    |

Note 1: Measured with 5 pF load

Note 2: Time between VDD rising above minimum operating voltage and stable frequency output

### Package Outline and Package Dimensions (8-pin DFN 2x2mm, 0.5mm pitch)

Package dimensions are kept current with JEDEC Publication No. 95,



|                | Millimeters |          |  |  |
|----------------|-------------|----------|--|--|
| Symbol         | Min         | Max      |  |  |
| Α              | 0.80        | 1.00     |  |  |
| A1             | 0           | 0.05     |  |  |
| A3             | 0.20 Re     | eference |  |  |
| b              | 0.20        | 0.30     |  |  |
| N              |             | 8        |  |  |
| N <sub>D</sub> | 4           |          |  |  |
| N <sub>E</sub> |             | 0        |  |  |
| D              | 2.00 [      | BASIC    |  |  |
| E              | 2.00 l      | BASIC    |  |  |
| е              | 0.50 I      | BASIC    |  |  |
| D2             | 1.05        | 1.25     |  |  |
| E2             | 0.45        | 0.65     |  |  |
| L              | 0.20 0.40   |          |  |  |
| aaa            | 0.15        |          |  |  |
| bbb            | 0.10        |          |  |  |
| ccc            | 0.          | 10       |  |  |

#### **Marking Diagram (8DFN)**

5

8

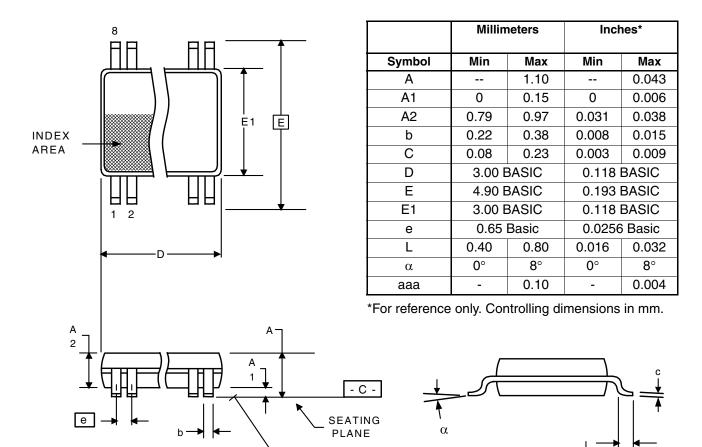


#### Notes:

- 1. Line 1: truncated part number (format to be the same for 912, 913, and 914 devices).
- 2. "G" designates Pb (lead) free package.
- 3. "I" denotes industrial temperature range.
- 4. "YYWW" is the last two digits of the year and week that the part was assembled.
- 5. "\$" is the mark code.
- 6. Bottom marking: country of origin.

## Package Outline and Package Dimensions (8-pin MSOP, 3.00 mm Body)

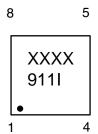
Package dimensions are kept current with JEDEC Publication No. 95



С

aaa

#### **Marking Diagram (8 MSOP)**



#### Notes:

- 1. "XXXX" is the lot sequence number.
- 2. Line 2: truncated part number (format to be the same for 912, 913, and 914 devices).
- 3. "I" denotes industrial temperature range.
- 4. Bottom marking: country of origin.

IDT5P50911/2/3/4

## **Ordering Information**

| Part / Order Number | Marking       | Shipping Packaging | Package    | Temperature    |
|---------------------|---------------|--------------------|------------|----------------|
| 5P50911NBGI8        |               | Tape and Reel      | 8-pin DFN  | -40°C to +85°C |
| 5P50911DVGI         |               | Tube               | 8-pin MSOP | -40°C to +85°C |
| 5P50911DVGI8        |               | Tape and Reel      | 8-pin MSOP | -40°C to +85°C |
| 5P50912NBGI8        |               | Tape and Reel      | 8-pin DFN  | -40°C to +85°C |
| 5P50912DVGI         |               | Tube               | 8-pin MSOP | -40°C to +85°C |
| 5P50912DVGI8        | 7.0           | Tape and Reel      | 8-pin MSOP | -40°C to +85°C |
| 5P50913NBGI8        | see pages 7,8 | Tape and Reel      | 8-pin DFN  | -40°C to +85°C |
| 5P50913DVGI         |               | Tube               | 8-pin MSOP | -40°C to +85°C |
| 5P50913DVGI8        |               | Tape and Reel      | 8-pin MSOP | -40°C to +85°C |
| 5P50914NBGI8        |               | Tape and Reel      | 8-pin DFN  | -40°C to +85°C |
| 5P50914DVGI         |               | Tube               | 8-pin MSOP | -40°C to +85°C |
| 5P50914DVGI8        |               | Tape and Reel      | 8-pin MSOP | -40°C to +85°C |

<sup>&</sup>quot;G" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

While the information presented herein has been checked for both accuracy and reliability, Integrated Device Technology (IDT) assumes no responsibility for either its use or for the infringement of any patents or other rights of third parties, which would result from its use. No other circuits, patents, or licenses are implied. This product is intended for use in normal commercial applications. Any other applications such as those requiring extended temperature range, high reliability, or other extraordinary environmental requirements are not recommended without additional processing by IDT. IDT reserves the right to change any circuitry or specifications without notice. IDT does not authorize or warrant any IDT product for use in life support devices or critical medical instruments.

## **Revision History**

| Rev. | Originator | Date     | Description of Change   |
|------|------------|----------|---|
| Α    | R. Willner | 11/10/11 | Initial release.  |
| В    | R. Willner | 12/5/11  | Revised pinout and modulation rate.   |
| С    | R. Willner | 4/6/12   | Crystal input only.  Added marking diagrams.  |
| D    | S. Sharma  | 7/02/14  | Changed Modulation Frequency formula and example (pg. 3) input frequency from 400MHz to 10000MHz. |
|      |            |          |   |

## Innovate with IDT and accelerate your future networks. Contact:

www.IDT.com

For Sales

800-345-7015 408-284-8200 Fax: 408-284-2775 For Tech Support

www.idt.com/go/clockhelp

#### **Corporate Headquarters**

Integrated Device Technology, Inc. www.idt.com

